

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Email & Skype: info@chipsmall.com Web: www.chipsmall.com

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High Voltage Fast-Switching NPN Power Transistor

FEATURES

- High Voltage Capability
- Fast Switching Speed
- Pb-free plating
- RoHS compliant
- Halogen-free mold compound

ΛВ	Ю	$\mathbf{I} \sim \mathbf{A}$	TION
AF		ILA	IION

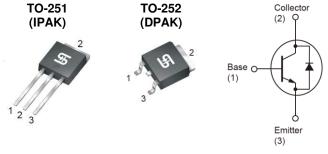
- Electronic Ballast
- Switch mode power supply

KEY PERFORMANCE PARAMETERS			
PA	RAMETER	VALUE	UNIT
BV _{CEO}		450	V
BV_CBO		1050	V
I _C		2.5	Α
V _{CE(SAT)}	V _{CE(SAT)} I _C =0.7A, I _B =0.14A 0.5		٧









Notes: Moisture sensitivity level: level 3. Per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Collector-Base Voltage	V _{CBO}	1050	V	
Collector-Emitter Voltage @ V _{BE} =0V	V _{CES}	450	V	
Emitter-Base Voltage	V _{EBO}	15	V	
Collector Current	I _C	2.5	Α	
Collector Peak Current (tp <5ms)	I _{CM}	4	Α	
Base Current	I _B	1.5	Α	
Base Peak Current (tp <5ms)	I _{BM}	3	Α	
Power Total Dissipation @ T _A =25°C	P _{DTOT}	30	W	
Maximum Operating Junction Temperature	TJ	+150	°C	
Storage Temperature Range	T _{STG}	-55 to +150	°C	

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction to Case Thermal Resistance	R _{eJC}	4.17	°C/W	
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	100	°C/W	

Version: B15





ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Collector-Base Voltage	I _C =0.5mA	BV _{CBO}	1050			V
Collector-Emitter Breakdown Voltage	I _C =5mA	BV _{CEO}	450			V
Emitter-Base Breakdown Voltage	I _E =1mA	BV _{EBO}	15			V
Collector Cutoff Current	$V_{CE} = 400V, I_{B} = 0$	I _{CEO}		10	250	μΑ
Collector Cutoff Current	$V_{CB} = 950V, I_{E} = 0$	I _{CBO}			10	μΑ
Collector-Emitter Saturation Voltage	I_{C} =0.7A, I_{B} =0.14A	V _{CE(SAT)} 1			0.5	V
Collector-Emitter Saturation Voltage	I _C =2A, I _B =0.6A	V _{CE(SAT)} 2		1.5	3.0	V
Base-Emitter Saturation Voltage	I _C =2A, I _B =0.6A	V _{BE(SAT)} 1		1.0	1.6	V
DC Current Coin	$V_{CE} = 5V, I_{C} = 0.1A$	h _{FE} 1	50	70	100	
DC Current Gain	$V_{CE} = 3V, I_{C} = 0.5A$	h _{FE} 2	18	23	50	
Diode Forward Voltage	I _C =1A	V _F			1.5	V
Rise Time (Note 2)		t _r			1	μs
Storage Time (Note 2)	$V_{CC} = 5V, I_{C} = 0.5A$	t _{STG}	2.5	3	3.5	μs
Fall Time (Note 2)		t _f			1.2	μs
Repetitive Avalanche Energy	L=2mH	E _{AR}	5			mJ

Notes:

- 1. Pulse test: ≤380µs, duty cycle ≤ 2%
- 2. For DESIGN AID ONLY, not subject to production testing.





ORDERING INFORMATION

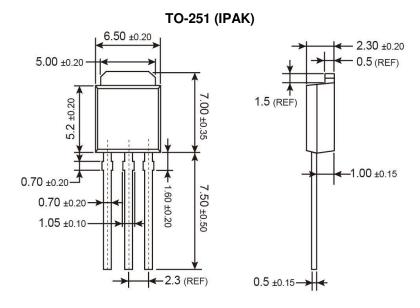
PART NO.	PACKAGE	PACKING		
TSC5802DCH C5G	TO-251	75pcs / Tube		
TSC5802DCP ROG	TO-252	2,500pcs / 13" Reel		

Note:

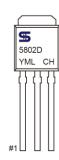
- 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



Marking Diagram



Y = Year Code

M = Month Code for Halogen Free Product

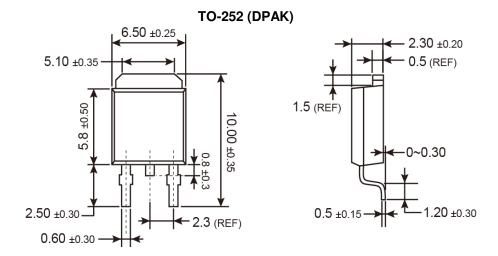
O =Jan P =Feb Q =Mar R =Apr S =May T =Jun U =Jul V =Aug

W = Sep X = Oct Y = Nov Z = Dec

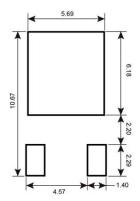
 $L = \text{Lot Code } (1 \sim 9, A \sim Z)$



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)



SUGGESTED PAD LAYOUT



MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product

O =Jan

P = Feb Q = Mar R = Apr

S =May **T** =Jun

V =Aug

W = Sep X = Oct

U =Jul

Y =Nov Z =Dec

L = Lot Code $(1\sim9, A\sim Z)$





Taiwan Semiconductor

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